



SMALL SIGNAL COMPLEMENTARY PRE-BIASED DUAL TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

R ₁ (Nom)	R ₂ (Nom)
22kΩ	22kΩ

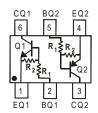
SOT363



Top View

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



Device Schematic

Ordering Information (Notes 4 & 5)

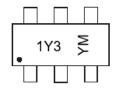
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ACX124EUQ-7R	Automotive	1Y3	7	8	3,000
ACX124EUQ-13R	Automotive	1Y3	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. -13R are parts rotated in the pocket tape by +180°. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT363



1Y3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Year	2016	2017	2018	2019	202	20 20)21	2022	2023	2024	2025	2026
Code	D	Е	F	G	Н		I	J	K	L	M	N
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings - NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <pin: (1)="" (6)="" to=""></pin:>	V _{CC}	50	V
Input Voltage <pin: (1)="" (2)="" to=""></pin:>	V _{IN}	-10 to +40	V
Output Current	l ₀	30	mA
Output Current	I _C (Max)	100	mA

Absolute Maximum Ratings - PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <pin: (3)="" (4)="" to=""></pin:>	V _{CC}	50	V
Input Voltage <pin: (4)="" (5)="" to=""></pin:>	V _{IN}	+10 to -40	V
Output Current	lo	-30	mA
Output Current	I _C (Max)	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

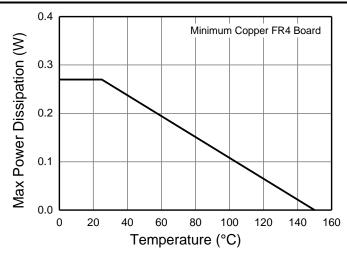
Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6 & 7)	P_{D}	270	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{ heta JA}$	450	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

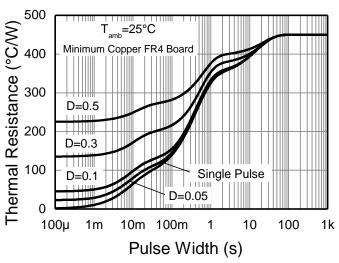
^{6.} Mounted on FR4 PC Board with minimum recommended pad layout 7. 150mW per element must not be exceeded.



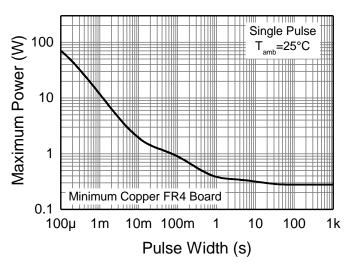
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics - NPN Section (@T_A = +25°C, unless otherwise specified.)

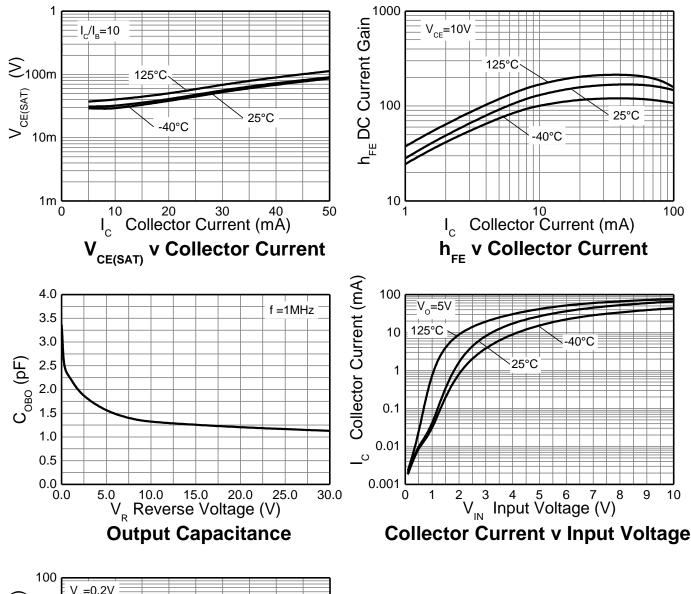
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	V _{I(OFF)}	0.5	1.1		V	$V_{CC} = 5V, I_{O} = 100\mu A$
input voltage	$V_{I(ON)}$	_	1.9	3.0	V	$V_O = 0.3V, I_O = 5mA$
Output Voltage	V _{O(ON)}	_	0.1	0.3	V	$I_{O}/I_{I} = 10mA / 0.5mA$
Input Current	l _l	_	_	0.36	mA	$V_I = 5V$
Output Current	I _{O(OFF)}	_	_	0.5	μΑ	$V_{CC} = 50V, V_{I} = 0V$
DC Current Gain	Gı	60	_	_	_	$V_{O} = 5V, I_{O} = 5mA$
Input Resistor (R ₁) Tolerance	ΔR_1	-30	_	+30	%	_
Resistance Ratio Tolerance	$\Delta R_2/R_1$	-20	_	+20	%	_
Gain-Bandwidth Product	f _T	_	250	_	MHz	$V_{CE} = 10V, I_{E} = 5mA, f = 100MHz$

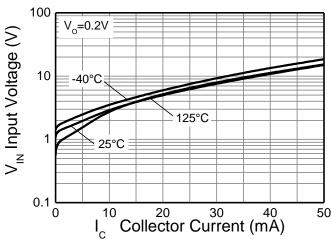
Electrical Characteristics - PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	V _{I(OFF)}	-0.5	-1.1	_	V	$V_{CC} = -5V, I_{O} = -100\mu A$
input voitage	V _{I(ON)}	_	-1.9	-3.0	V	$V_O = -0.3V$, $I_O = -5mA$
Output Voltage	V _{O(ON)}	_	-0.1	-0.3	V	$I_O/I_I = -10mA / -0.5mA$
Input Current	II	_		-0.36	mA	$V_I = -5V$
Output Current	I _{O(OFF)}	_		-0.5	μΑ	$V_{CC} = 50V, V_{I} = 0V$
DC Current Gain	Gı	60	_	_	_	$V_0 = -5V, I_0 = -5mA$
Input Resistor (R ₁) Tolerance	ΔR_1	-30	_	+30	%	_
Resistance Ratio Tolerance	$\Delta R_2/R_1$	-20	_	+20	%	_
Gain-Bandwidth Product	f _T	_	250	_	MHz	$V_{CE} = -10V$, $I_{E} = -5mA$, $f = 100MHz$



Typical Electrical Characteristics - NPN Section (@T_A = +25°C, unless otherwise specified.)

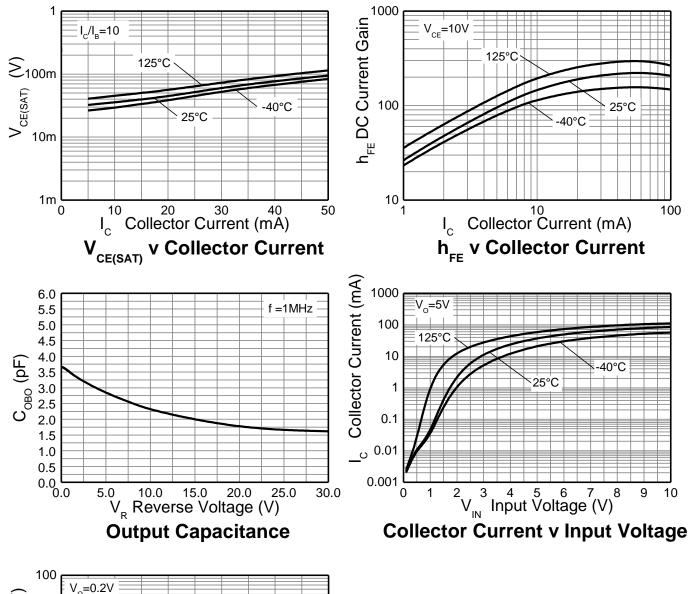


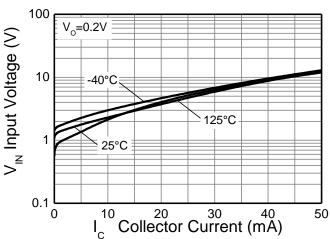


Input Voltage v Collector Current



Typical Electrical Characteristics – PNP Section (@TA = +25°C, unless otherwise specified.)





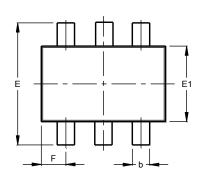
Input Voltage v Collector Current

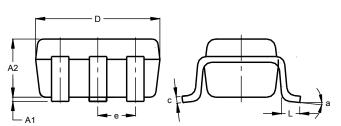


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



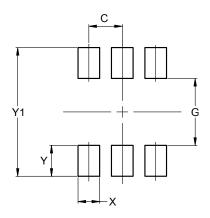


SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
C	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 B	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value
	(in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500



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NSVDTC143ZM3T5G SMUN5216DW1T1G NSVMUN5312DW1T2G NSVMUN5215DW1T1G